Integrated Device Technology, Inc.

FAST CMOS 1-TO-10 CLOCK DRIVER

IDT54/74FCT807BT/CT

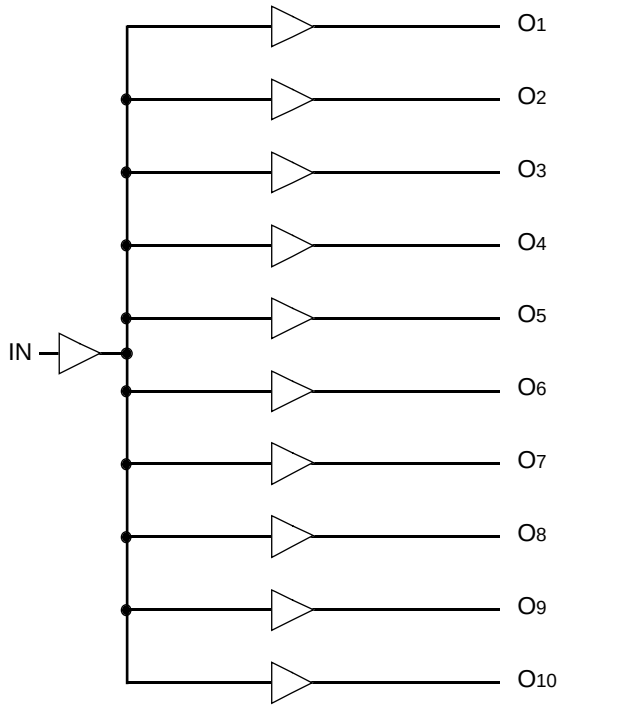
FEATURES:

- 0.5 MICRON CMOS Technology
- Guaranteed low skew < 250ps (max.)
- Very low duty cycle distortion < 350ps (max.)
- High speed: propagation delay < 2.5ns (max.)
- 100MHz operation
- TTL compatible inputs and outputs
- TTL level output voltage swings
- 1:10 fanout
- Output rise and fall time < 1.5ns (max.)
- Low input capacitance: 4.5pF typical
- High Drive: -32mA I_{OH}, 48mA I_{OL}
- ESD > 2000V per MIL STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- Available in DIP, SOIC, SSOP, QSOP, Cerpack and LCC packages
- Military product compliant to MIL-STD-883, Class B

DESCRIPTION:

The IDT54/74FCT807BT/CT clock driver is built using advanced dual metal CMOS technology. This low skew clock driver features 1:10 fanout, providing minimal loading on the preceding drivers. The IDT54/74FCT807BT/CT offers low capacitance inputs with hysteresis for improved noise margins. TTL level outputs and multiple power and grounds reduce noise. The device also features -32/48mA drive capability for driving low impedance traces.

FUNCTIONAL BLOCK DIAGRAM



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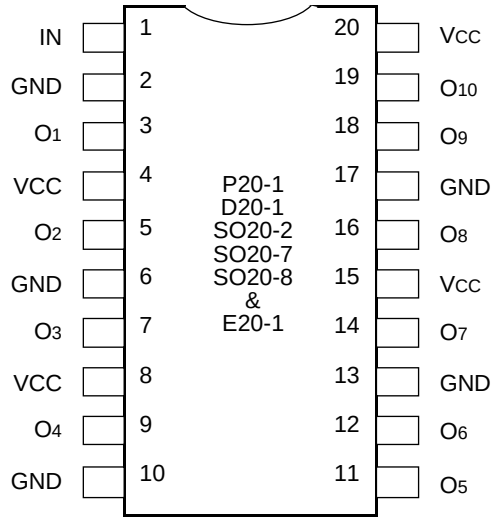
PIN CONFIGURATIONS



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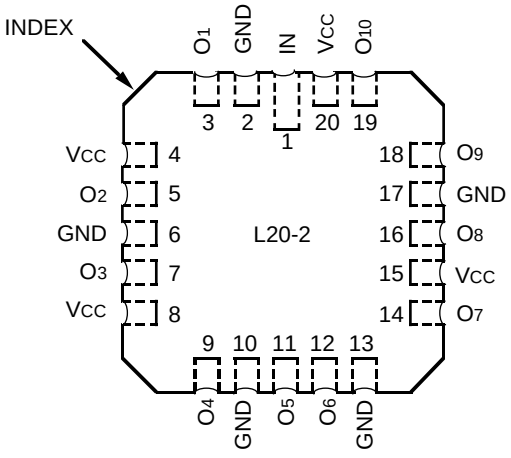
DIP/SOIC/SSOP/QSOP/CERPACK TOP VIEW



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LCC TOP VIEW

PIN DESCRIPTION

Pin Names	Description
IN	Input
Ox	Outputs

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CAPACITANCE (T_A = +25°C, f = 1.0MHz)

Symbol	Parameter(1)	Conditions	Typ.	Max.	Unit
C_{IN}	Input Capacitance	V_{IN} = 0V	4.5	6.0	pF
C_{OUT}	Output Capacitance	V_{OUT} = 0V	5.5	8.0	pF

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NOTE:
1. This parameter is measured at characterization but not tested.

ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Rating	Commercial	Military	Unit
V_{TERM}(2)	Terminal Voltage with Respect to GND	–0.5 to +7.0	–0.5 to +7.0	V
V_{TERM}(3)	Terminal Voltage with Respect to GND	–0.5 to V_{CC} +0.5	–0.5 to V_{CC} +0.5	V
T_A	Operating Temperature	0 to +70	–55 to +125	°C
T_{BIAS}	Temperature Under Bias	–55 to +125	–65 to +135	°C
T_{STG}	Storage Temperature	–55 to +125	–65 to +150	°C
I_{OUT}	DC Output Current	–60 to +120	–60 to +120	mA

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NOTES:
1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability. No terminal voltage may exceed V_{CC} by +0.5V unless otherwise noted.
2. Input and V_{CC} terminals.
3. Output and I/O terminals.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified
Commercial: T_A = 0°C to +70°C, V_{CC} = 5.0V ± 5%; Military: T_A = –55°C to +125°C, V_{CC} = 5.0V ± 10%

Symbol	Parameter	Test Conditions[1]		Min.	Typ.[2]	Max.	Unit
V_{IH}	Input HIGH Level	Guaranteed Logic HIGH Level		2.0	—	—	V
V_{IL}	Input LOW Level	Guaranteed Logic LOW Level		—	—	0.8	V
I_{IH}	Input HIGH Current[5]	V_{CC} = Max.	V_I = 2.7V	—	—	±1	µA
I_{IL}	Input LOW Current[5]	V_{CC} = Max.	V_I = 0.5V	—	—	±1	µA
I_{OZH}	High Impedance Output Current	V_{CC} = Max.	V_O = 2.7V	—	—	±1	µA
I_{OZL}	(3-State Output pins)[5]		V_O = 0.5V	—	—	±1	µA
I_I	Input HIGH Current[5]	V_{CC} = Max., V_I = V_{CC} (Max.)		—	—	±1	µA
V_{IK}	Clamp Diode Voltage	V_{CC} = Min., I_{IN} = –18mA		—	–0.7	–1.2	V
I_{OS}	Short Circuit Current	V_{CC} = Max.[3], V_O = GND		–60	–120	–225	mA
V_{OH}	Output HIGH Voltage	V_{CC} = Min. V_{IN} = V_{IH} or V_{IL}	I_{OH} = –12mA MIL. I_{OH} = –15mA COM'L.	2.4	3.3	—	V
			I_{OH} = –24mA MIL. I_{OH} = –32mA COM'L.[4]	2.0	3.0	—	
V_{OL}	Output LOW Voltage	V_{CC} = Min. V_{IN} = V_{IH} or V_{IL}	I_{OL} = 32mA MIL. I_{OL} = 48mA COM'L.	—	0.3	0.55	V
I_{OFF}	Input/Output Power Off Leakage[5]	V_{CC} = 0V, V_{IN} or V_O ≤ 4.5V		—	—	±1	µA
V_H	Input Hysteresis for all inputs	—		—	150	—	mV
I_{CCL} I_{CCH} I_{CCZ}	Quiescent Power Supply Current	V_{CC} = Max., V_{IN} = GND or V_{CC}		—	5	500	µA

NOTES: 3017 lnk 04

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at Vcc = 5.0V, +25°C ambient.
3. Not more than one output should be tested at one time. Duration of the test should not exceed one second.
4. Duration of the condition can not exceed one second.
5. The test limit for this parameter is ± 5µA at T_A = –55°C.

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions[1]		Min.	Typ.[2]	Max.	Unit
ΔI_{CC}	Quiescent Power Supply Current TTL Inputs HIGH	V_{CC} = Max. V_{IN} = 3.4V		—	0.5	2.0	mA
I_{CCD}	Dynamic Power Supply Current[3]	V_{CC} = Max. Input toggling 50% Duty Cycle Outputs Open	V_{IN} = V_{CC} V_{IN} = GND	—	0.4	0.6	mA/ MHz
I_C	Total Power Supply Current[5]	V_{CC} = Max. Input toggling 50% Duty Cycle Outputs Open fi = 50MHz	V_{IN} = V_{CC} V_{IN} = GND	—	20.0	30.5[4]	mA
			V_{IN} = 3.4V V_{IN} = GND	—	20.3	31.3[4]	

NOTES: 3017 tbl 05

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at V_{CC} = 5.0V, +25°C ambient.
3. Per TTL driven input; (V_{IN} = 3.4V); all other inputs at V_{CC} or GND.
4. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
5. Values for these conditions are examples of the I_{CC} formula. These limits are guaranteed but not tested.
6. $I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$
   $I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_i)$
   I_{CC} = Quiescent Current (I_{CCL}, I_{CCH} and I_{CCZ})
   ΔI_{CC} = Power Supply Current for a TTL High Input (V_{IN} = 3.4V)
   D_H = Duty Cycle for TTL Inputs High
   N_T = Number of TTL Inputs at D_H
   I_{CCD} = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)
   f_i= Input Frequency
   All currents are in milliamps and all frequencies are in megahertz.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE[3,4]

Symbol	Parameter	Conditions[1]	IDT54/74FCT807BT				IDT54/74FCT807CT				Unit
			Com'l.		Mil.		Com'l.		Mil.		
			Min.[2]	Max.	Min.[2]	Max.	Min.[2]	Max.	Min.[2]	Max.	
t_{PLH} t_{PHL}	Propagation Delay	50Ω to V_{CC}/2, C_L = 10pF	1.3	2.7			1.3	2.5			ns
t_R	Output Rise Time	(See figure 1)	—	1.5	—		—	1.5	—		ns
t_F	Output Fall Time	or 50Ω ac	—	1.5	—		—	1.5	—		ns
t_{SK}(o)	Output skew: skew between outputs of same package (same transition)	termination, C_L = 10pF	—	0.5	—		—	0.25	—		ns
t_{SK}(p)	Pulse skew: skew between opposite transitions of same output (|t_{PHL} – t_{PLH}|)	(See figure 2) f ≤ 100MHz	—	0.5	—		—	0.35	—		ns
t_{SK}(t)	Package skew: skew between outputs of different packages at same power supply voltage, temperature, package type and speed grade	Outputs connected in groups of two	—	0.9	—		—	0.65	—		ns

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Symbol	Parameter	Conditions[1]	IDT54/74FCT807BT				IDT54/74FCT807CT				Unit
			Com'l.		Mil.		Com'l.		Mil.		
			Min.[2]	Max.	Min.[2]	Max.	Min.[2]	Max.	Min.[2]	Max.	
t_{PLH} t_{PHL}	Propagation Delay	C_L = 30pF f ≤ 67MHz	1.5	3.8			1.5	3.5			ns
t_R	Output Rise Time	(See figure 3)	—	1.5	—		—	1.5	—		ns
t_F	Output Fall Time		—	1.5	—		—	1.5	—		ns
t_{SK}(o)	Output skew: skew between outputs of same package (same transition)		—	0.5	—		—	0.25	—		ns
t_{SK}(p)	Pulse skew: skew between opposite transitions of same output (|t_{PHL} – t_{PLH}|)		—	0.5	—		—	0.35	—		ns
t_{SK}(t)	Package skew: skew between outputs of different packages at same power supply voltage, temperature, package type and speed grade		—	0.9	—		—	0.75	—		ns

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Symbol	Parameter	Conditions[1]	IDT54/74FCT807BT				IDT54/74FCT807CT				Unit
			Com'l.		Mil.		Com'l.		Mil.		
			Min.[2]	Max.	Min.[2]	Max.	Min.[2]	Max.	Min.[2]	Max.	
t_{PLH} t_{PHL}	Propagation Delay	C_L = 50pF f ≤ 40MHz	1.5	3.8			1.5	3.5			ns
t_R	Output Rise Time	(See figure 4)	—	1.5	—		—	1.5	—		ns
t_F	Output Fall Time		—	1.5	—		—	1.5	—		ns
t_{SK}(o)	Output skew: skew between outputs of same package (same transition)		—	0.5	—		—	0.35	—		ns
t_{SK}(p)	Pulse skew: skew between opposite transitions of same output (|t_{PHL} – t_{PLH}|)		—	0.60	—		—	0.45	—		ns
t_{SK}(t)	Package skew: skew between outputs of different packages at same power supply voltage, temperature, package type and speed grade		—	1.0	—		—	0.75	—		ns

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NOTES:
1. See test circuits and waveforms.
2. Minimum limits are guaranteed but not tested on Propagation Delays.
3. t_{PLH}, t_{PHL}, t_{SK}(t) are production tested. All other parameters guaranteed but not production tested.
4. Propagation delay range indicated by Min. and Max. limit is due to V_{CC}, operating temperature and process parameters. These propagation delay limits do not imply skew.

TEST CIRCUITS

50Ω TO VCC/2, CL = 10pF

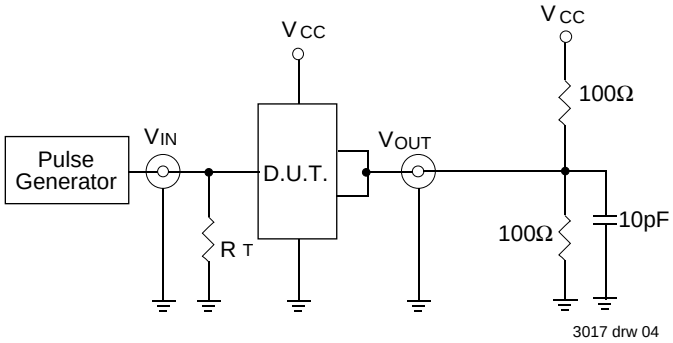
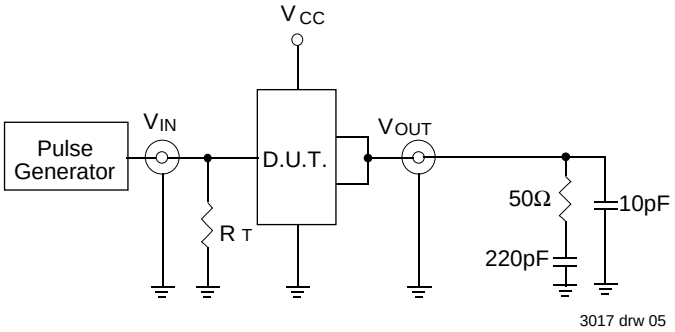


Figure 1.

50Ω AC TERMINATION, CL = 10pF



The capacitor value for ac termination is determined by the operating frequency. For very low frequencies a higher capacitor value should be selected.

Figure 2.

CL = 30pF CIRCUIT

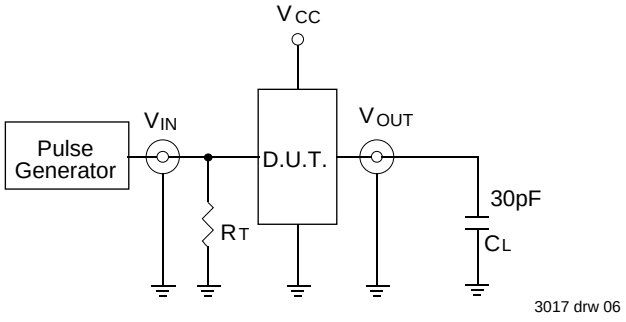


Figure 3.

CL = 50pF CIRCUIT

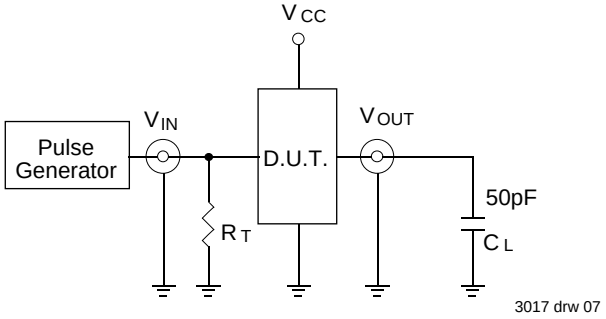


Figure 4.

ENABLE AND DISABLE TIME CIRCUIT

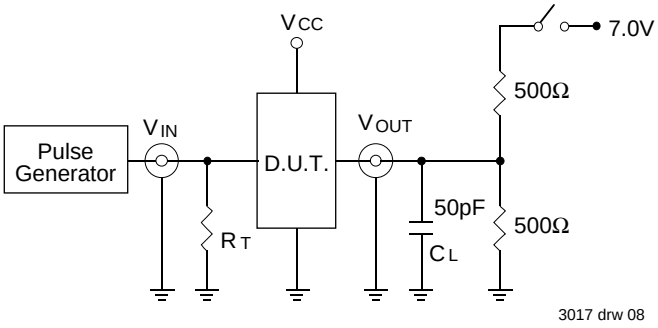


Figure 5.

ENABLE AND DISABLE TIME SWITCH POSITION

Test	Switch
Disable LOW Enable LOW	Closed
Disable HIGH Enable HIGH	Open

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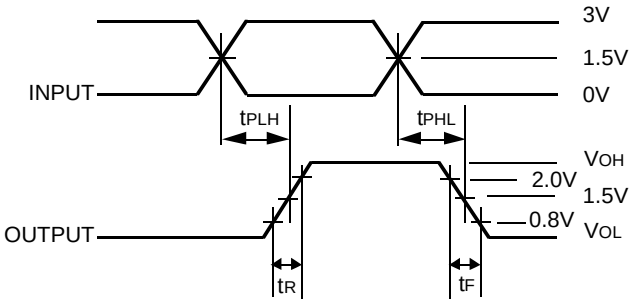
DEFINITIONS:

CL= Load capacitance: includes jig and probe capacitance.
RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.

TEST WAVEFORMS

PACKAGE DELAY



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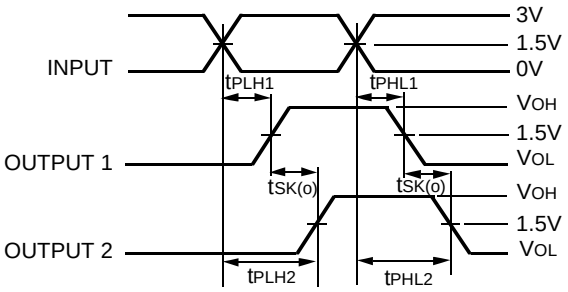
OUTPUT SKEW- tSK(o)



$t_{SK(o)} = |t_{PLH2} - t_{PLH1}|$ or $|t_{PHL2} - t_{PHL1}|$

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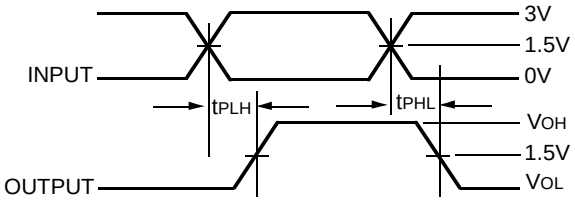
PULSE SKEW - tSK(p)



$t_{SK(p)} = |t_{PHL} - t_{PLH}|$

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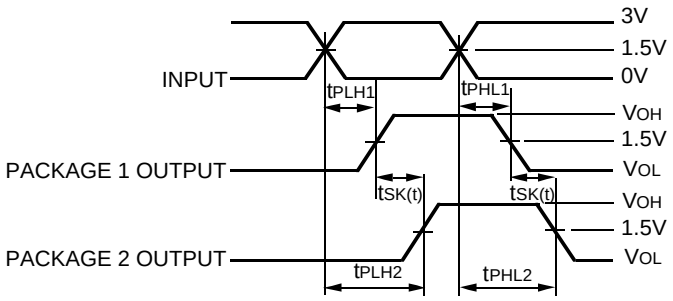
PACKAGE SKEW - tSK(t)



$t_{SK(t)} = |t_{PLH2} - t_{PLH1}|$ or $|t_{PHL2} - t_{PHL1}|$

Package 1 and Package 2 are same device type and speed grade

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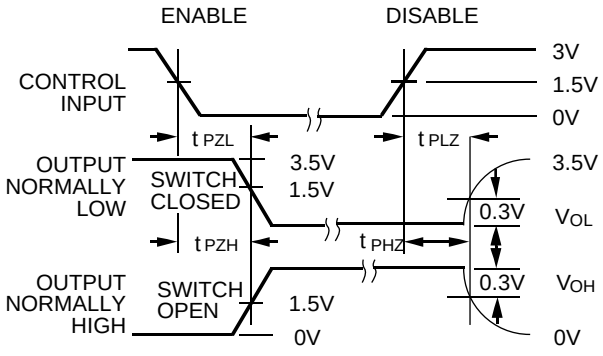
ENABLE AND DISABLE TIMES



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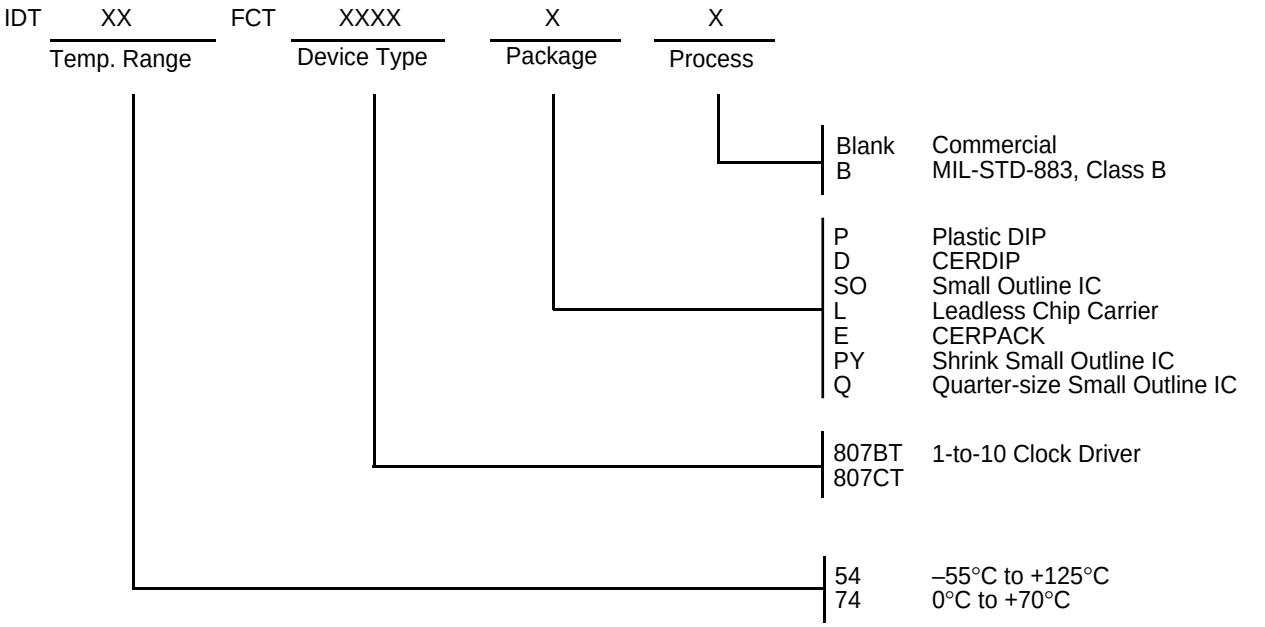
NOTES:
1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH
2. Pulse Generator for All Pulses: f ≤ 1.0MHz; t_F ≤ 2.5ns; t_R ≤ 2.5ns

ORDERING INFORMATION



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